PMEG1020EH; PMEG1020EJ

10 V, 2 A ultra low V_F MEGA Schottky barrier rectifiers
Rev. 04 — 15 January 2010 Product d

Product data sheet

Product profile 1.

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifiers with an integrated guard ring for stress protection, encapsulated in small and flat lead plastic SMD packages.

Table 1. **Product overview**

Type number	Package		Configuration
	NXP	JEITA	
PMEG1020EH	SOD123F	-	single diode
PMEG1020EJ	SOD323F	SC-90	single diode

1.2 Features

Forward current: ≤ 2 A

■ Reverse voltage: ≤ 10 V

Ultra low forward voltage

Small and flat lead SMD plastic packages

1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Inverse polarity protection
- Low power consumption applications

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _F	forward current	$T_{sp} \leq 55 ^{\circ}C$	-	-	2	Α
V_R	reverse voltage		-	-	10	V
V_{F}	forward voltage	I _F = 2 A	[1] _	350	460	mV

^[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$.



2. Pinning information

Table 3. Pinning

10010 01	9	
Pin	Description	Simplified outline Symbol
1	cathode	[1]
2	anode	1 2 2 sym001 001aab540

^[1] The marking bar indicates the cathode.

3. Ordering information

Table 4. Ordering information

Type number	Package	Package		
	Name	Description	Version	
PMEG1020EH	-	plastic surface mounted package; 2 leads	SOD123F	
PMEG1020EJ	SC-90	plastic surface mounted package; 2 leads	SOD323F	

4. Marking

Table 5. Marking codes

Type number	Marking code
PMEG1020EH	A8
PMEG1020EJ	СВ

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

			-		
Symbol	Parameter	Conditions	Min	Max	Unit
V_R	reverse voltage		-	10	V
I _F	forward current	$T_{sp} \le 55 ^{\circ}C$	-	2	Α
I _{FRM}	repetitive peak forward current	$t_p \le 1$ ms; $\delta \le 0.5$	-	7	Α
I _{FSM}	non-repetitive peak forward current	square wave; t _p = 8 ms	-	9	Α
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$			
	PMEG1020EH		<u>[1]</u> _	375	mW
			[2] _	830	mW
	PMEG1020EJ		<u>[1]</u>	360	mW
			[2] _	830	mW
Ti	junction temperature		-	150	°C

Table 6. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
T_{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air					
	PMEG1020EH		[1][2]	-	-	330	K/W
			[2][3]	-	-	150	K/W
	PMEG1020EJ		[1][2]	-	-	350	K/W
			[2][3]	-	-	150	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		<u>[4]</u>				
	PMEG1020EH			-	-	60	K/W
	PMEG1020EJ			-	-	55	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	forward voltage	$I_F = 0.01 A$	<u>[1]</u> -	100	130	mV
		I _F = 0.1 A	<u>[1]</u> _	170	200	mV
		I _F = 1 A	<u>[1]</u> _	280	350	mV
		I _F = 2 A	<u>[1]</u> _	350	460	mV
I_R	reverse current	$V_R = 5 V$	-	0.7	2	mA
		V _R = 8 V	-	1	2.5	mA
		V _R = 10 V	-	1.2	3	mA
C_{d}	diode capacitance	$V_R = 5 V$; $f = 1 MHz$	-	40	50	pF

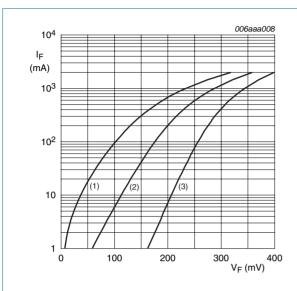
^[1] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

^[2] For Schottky barrier rectifiers thermal run-away has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses. Nomograms for determining the reverse power losses P_R and I_{F(AV)} rating are available on request.

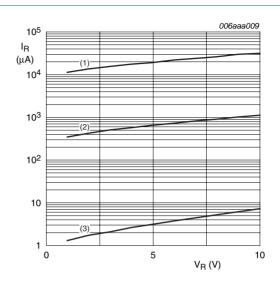
^[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

^[4] Soldering point of cathode tab.



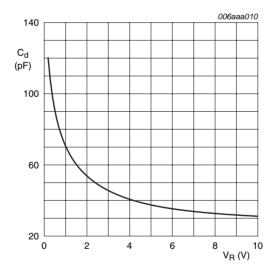
- (1) $T_{amb} = 85 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -40 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values



- (1) $T_{amb} = 85 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -40 \, ^{\circ}C$

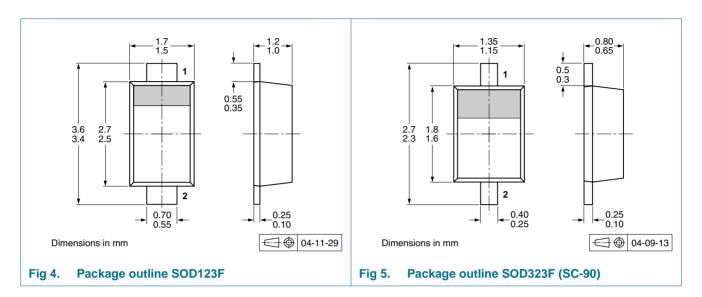
Fig 2. Reverse current as a function of reverse voltage; typical values



 $T_{amb} = 25 \, ^{\circ}C; f = 1 \, MHz$

Fig 3. Diode capacitance as a function of reverse voltage; typical values

8. Package outline



9. Packing information

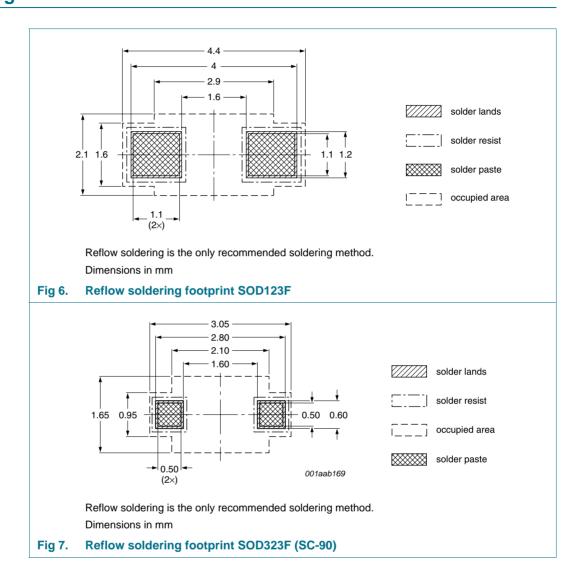
Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing 6	quantity
			3000	10000
PMEG1020EH	SOD123F	4 mm pitch, 8 mm tape and reel	-115	-135
PMEG1020EJ	SOD323F			

[1] For further information and the availability of packing methods, see Section 13.

10. Soldering



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11. Revision history

Table 10. Revision history

Product data sheet

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG1020EH_EJ_4	20100115	Product data sheet	-	PMEG1020EH_EJ_3
Modifications:		eet was changed to reflect t v legal definitions and discla		
PMEG1020EH_EJ_3	20050414	Product data sheet	-	PMEG1020EJ_2; PMEG1020EH_1
PMEG1020EJ_2	20041001	Product data sheet	-	PMEG1020EJ_1
PMEG1020EH_1	20050203	Objective data sheet	-	-

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12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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